

RoHS Sxx10xSx & Sxx10x Series



Description

Excellent unidirectional switches for phase control and general switching applications such as heating and motor speed controls.

Sensitive gate SCRs are easily triggered with microAmps of current as furnished by sense coils, proximity switches, and microprocessors.

Standard phase control SCRs are triggered with few milliamperes of current at less than 1.5V potential.

Features & Benefits

- RoHS compliant
- Glass – passivated junctions
- Voltage capability up to 1000 V
- Surge capability up to 100 A

Applications

Typical applications are capacitive discharge systems for strobe lights, nailers, staplers and gas engine ignition. Also controls for power tools, home/brown goods and white goods appliances.

Internally constructed isolated packages are offered for ease of heat sinking with highest isolation voltage.

Agency Approval

Agency	Agency File Number
	TO-220L Package : E71639

Main Features

Symbol	Value	Unit
$I_{T(RMS)}$	10	A
V_{DRM}/V_{RRM}	400 to 1000	V
I_{GT}	0.2 to 15	mA

Schematic Symbol



Absolute Maximum Ratings – Sensitive SCRs

Symbol	Parameter	Test Conditions		Value	Unit
$I_{T(RMS)}$	RMS on-state current	Sxx10LSy	$T_c = 80^\circ\text{C}$	10	A
		Sxx10RSy Sxx10DSy Sxx10Vsy	$T_c = 95^\circ\text{C}$		
$I_{T(AV)}$	Average on-state current	Sxx10LSy	$T_c = 80^\circ\text{C}$	6.4	A
		Sxx10RSy Sxx10DSy Sxx10Vsy	$T_c = 95^\circ\text{C}$		
I_{TSM}	Peak non-repetitive surge current	single half cycle; $f = 50\text{Hz}$; T_J (initial) = 25°C		83	A
		single half cycle; $f = 60\text{Hz}$; T_J (initial) = 25°C		100	
I^2t	I^2t Value for fusing	$t_p = 8.3 \text{ ms}$		41	A^2s
di/dt	Critical rate of rise of on-state current	$f = 60 \text{ Hz}$; $T_J = 110^\circ\text{C}$		100	$\text{A}/\mu\text{s}$
I_{GM}	Peak gate current	$T_J = 110^\circ\text{C}$		1	A
$P_{G(AV)}$	Average gate power dissipation	$T_J = 110^\circ\text{C}$		0.1	W
T_{stg}	Storage temperature range			-40 to 150	$^\circ\text{C}$
T_J	Operating junction temperature range			-40 to 110	$^\circ\text{C}$

Note: xx = voltage, y = sensitivity

Absolute Maximum Ratings – Standard SCRs

Symbol	Parameter	Test Conditions		Value	Unit
$I_{T(RMS)}$	RMS on-state current	Sxx10L	$T_c = 95^\circ\text{C}$	10	A
		Sxx10R Sxx10D Sxx10V	$T_c = 105^\circ\text{C}$		
$I_{T(AV)}$	Average on-state current	Sxx10L	$T_c = 95^\circ\text{C}$	6.4	A
		Sxx10R Sxx10D Sxx10V	$T_c = 105^\circ\text{C}$		
I_{TSM}	Peak non-repetitive surge current	single half cycle; $f = 50\text{Hz}$; T_J (initial) = 25°C		83	A
		single half cycle; $f = 60\text{Hz}$; T_J (initial) = 25°C		100	
I^2t	I^2t Value for fusing	$t_p = 8.3 \text{ ms}$		41	A^2s
di/dt	Critical rate-of-rise of on-state current	$f = 60 \text{ Hz}$; $T_J = 125^\circ\text{C}$		100	$\text{A}/\mu\text{s}$
I_{GM}	Peak gate current	$T_J = 125^\circ\text{C}$		2	A
$P_{G(AV)}$	Average gate power dissipation	$T_J = 125^\circ\text{C}$		0.5	W
T_{stg}	Storage temperature range			-40 to 150	$^\circ\text{C}$
T_J	Operating junction temperature range			-40 to 125	$^\circ\text{C}$

Note: xx = voltage

Electrical Characteristics ($T_J = 25^\circ\text{C}$, unless otherwise specified) – Sensitive SCRs

Symbol	Test Conditions		Value		Unit
			Sxx10xS2	Sxx10xS3	
I_{GT}	$V_D = 6V$ $R_L = 100 \Omega$	MAX.	200	500	μA
V_{GT}		MAX.	0.8		V
dv/dt	$V_D = V_{DRM}$; $R_{GK} = 1k\Omega$; $T_J = 110^\circ\text{C}$	TYP.	8		V/ μs
V_{GD}	$V_D = V_{DRM}$; $R_L = 3.3 k\Omega$; $T_J = 110^\circ\text{C}$	MIN.	0.2		V
V_{GRM}	$I_{GR} = 10\mu\text{A}$	MIN.	6		V
I_H	$I_T = 20\text{mA}$ (initial)	MAX.	6	8	mA
t_q	(1)	MAX.	50	45	μs
t_{gt}	$I_G = 2 \times I_{GT}$; $PW = 15\mu\text{s}$; $I_T = 12\text{A}$	TYP.	4	5	μs

NOTE: xx = voltage, x = package

(1) $I_T=2\text{A}$; $t_p=50\mu\text{s}$; $dv/dt=5\text{V}/\mu\text{s}$; $di/dt=-30\text{A}/\mu\text{s}$

Electrical Characteristics ($T_J = 25^\circ\text{C}$, unless otherwise specified) – Standard SCRs

Symbol	Test Conditions			Value	Unit	
				Sxx10x		
I_{GT}	$V_D = 12V$ $R_L = 60 \Omega$		MAX.	15	mA	
V_{GT}			MAX.	1.5	V	
dv/dt	$V_D = V_{DRM}$; gate open; $T_J = 100^\circ\text{C}$	400V	MIN.	350	V/ μs	
		600V		300		
		800V		250		
		1000V		100		
		$V_D = V_{DRM}$; gate open; $T_J = 125^\circ\text{C}$		400V		250
				600V		225
800V	200					
V_{GD}	$V_D = V_{DRM}$; $R_L = 3.3 k\Omega$; $T_J = 125^\circ\text{C}$		MIN.	0.2	V	
I_H	$I_T = 200\text{mA}$ (initial)		MAX.	30	mA	
t_q	(1)		MAX.	35	μs	
t_{gt}	$I_G = 2 \times I_{GT}$; $PW = 15\mu\text{s}$; $I_T = 20\text{A}$		TYP.	2	μs	

NOTE: xx = voltage, x = package

(1) $I_T=2\text{A}$; $t_p=50\mu\text{s}$; $dv/dt=5\text{V}/\mu\text{s}$; $di/dt=-30\text{A}/\mu\text{s}$

Static Characteristics

Symbol	Test Conditions		Value	Unit	
V_{TM}	$I_T = 20\text{A}$; $t_p = 380 \mu\text{s}$		MAX.	1.6 V	
I_{DRM} / I_{RRM}	V_{DRM} / V_{RRM}	Sxx10xyy	$T_J = 25^\circ\text{C}$	400 - 600V	5
			$T_J = 110^\circ\text{C}$	400 - 600V	250
		Sxx10x	$T_J = 25^\circ\text{C}$	400 - 800V	10
				1000V	20
			$T_J = 100^\circ\text{C}$	400 - 800V	200
				1000V	3000
$T_J = 125^\circ\text{C}$	400 - 800V	500			

Note: xx = voltage, x = package, yy = sensitivity

Thermal Resistances

Symbol	Parameter	Value	Unit	
$R_{\theta(J-C)}$	Junction to case (AC)	Sxx10RSy	1.6	°C/W
		Sxx10LSy	3.0	
		Sxx10Vsy	1.7	
		Sxx10DSy	1.45	
		Sxx10R	1.6	
		Sxx10L	3.0	
		Sxx10V	1.7	
		Sxx10D	1.45	
$R_{\theta(J-A)}$	Junction to ambient	Sxx10RSy	40	°C/W
		Sxx10LSy	65	
		Sxx10Vsy	85	
		Sxx10R	40	
		Sxx10L	50	
		Sxx10V	70	

Note: xx = voltage, y = sensitivity

Figure 1: Normalized DC Gate Trigger Current vs. Junction Temperature (Sensitive SCR)



Figure 2: Normalized DC Gate Trigger Current vs. Junction Temperature (Standard SCR)



Figure 3: Normalized DC Gate Trigger Voltage vs. Junction Temperature



Figure 4: Normalized DC Holding Current vs. Junction Temperature

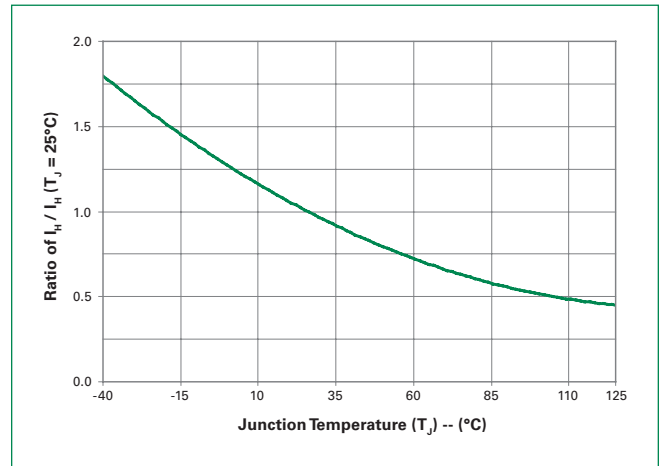


Figure 5: On-State Current vs. On-State Voltage (Typical)



Figure 6: Power Dissipation (Typical) vs. RMS On-State Current

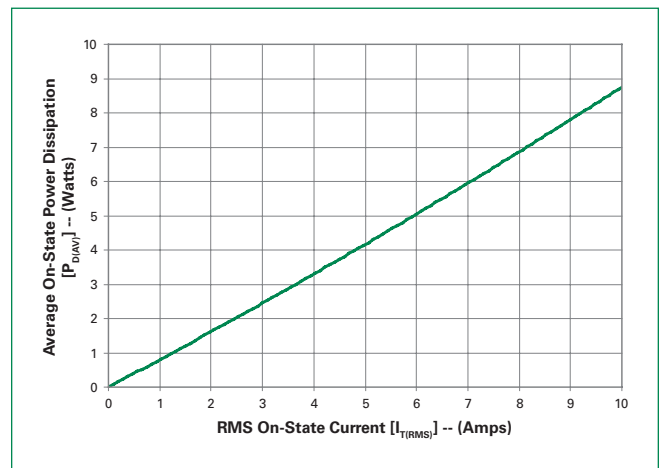


Figure 7: Maximum Allowable Case Temperature vs. RMS On-State Current



Figure 8: Maximum Allowable Case Temperature vs. Average On-State Current

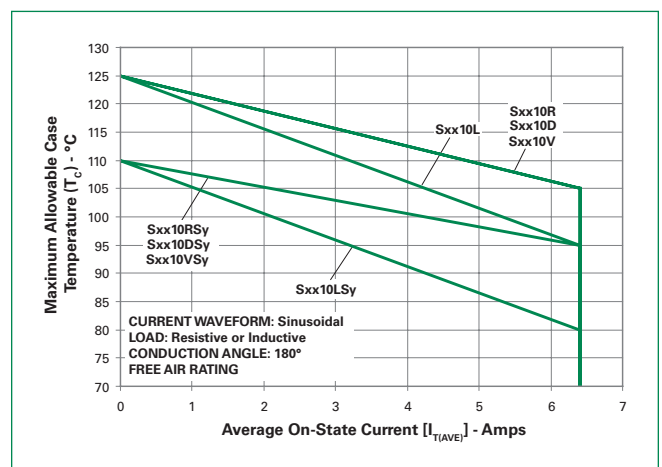


Figure 9: Maximum Allowable Ambient Temperature vs. RMS On-State Current



Note: xx = voltage, y = sensitivity

Figure 10: Maximum Allowable Ambient Temperature vs. Average On-State Current



Figure 11: Peak Capacitor Discharge Current



Figure 12: Peak Capacitor Discharge Current Derating



Figure 13: Surge Peak On-State Current vs. Number of Cycles



Soldering Parameters

Reflow Condition		Pb – Free assembly
Pre Heat	- Temperature Min ($T_{s(min)}$)	150°C
	- Temperature Max ($T_{s(max)}$)	200°C
	- Time (min to max) (t_s)	60 – 180 secs
Average ramp up rate (Liquidus Temp (T_L) to peak)		5°C/second max
$T_{s(max)}$ to T_L - Ramp-up Rate		5°C/second max
Reflow	- Temperature (T_L) (Liquidus)	217°C
	- Temperature (t_L)	60 – 150 seconds
Peak Temperature (T_p)		260 ^{+0/-5} °C
Time within 5°C of actual peak Temperature (t_p)		20 – 40 seconds
Ramp-down Rate		5°C/second max
Time 25°C to peak Temperature (T_p)		8 minutes Max.
Do not exceed		280°C



Physical Specifications

Terminal Finish	100% Matte Tin-plated
Body Material	UL recognized epoxy meeting flammability classification 94V-0
Lead Material	Copper Alloy

Design Considerations

Careful selection of the correct device for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Good design practice should limit the maximum continuous current through the main terminals to 75% of the device rating. Other ways to ensure long life for a power discrete semiconductor are proper heat sinking and selection of voltage ratings for worst case conditions. Overheating, overvoltage (including dv/dt), and surge currents are the main killers of semiconductors. Correct mounting, soldering, and forming of the leads also help protect against component damage.

Environmental Specifications

Test	Specifications and Conditions
AC Blocking	MIL-STD-750, M-1040, Cond A Applied Peak AC voltage @ 125°C for 1008 hours
Temperature Cycling	MIL-STD-750, M-1051, 100 cycles; -40°C to +150°C; 15-min dwell-time
Temperature/Humidity	EIA / JEDEC, JESD22-A101 1008 hours; 320V - DC; 85°C; 85% rel humidity
High Temp Storage	MIL-STD-750, M-1031, 1008 hours; 150°C
Low-Temp Storage	1008 hours; -40°C
Thermal Shock	MIL-STD-750, M-1056 10 cycles; 0°C to 100°C; 5-min dwell-time at each temperature; 10 sec (max) transfer time between temperature
Autoclave	EIA / JEDEC, JESD22-A102 168 hours (121°C at 2 ATMs) and 100% R/H
Resistance to Solder Heat	MIL-STD-750 Method 2031
Solderability	ANSI/J-STD-002, category 3, Test A
Lead Bend	MIL-STD-750, M-2036 Cond E

Product Selector

Part Number	Voltage				Gate Sensitivity	Type	Package
	400V	600V	800V	1000V			
Sxx10RS2	X	X			0.2mA	Sensitive SCR	TO-220R
Sxx10LS2	X	X			0.2mA	Sensitive SCR	TO-220L
Sxx10VS2	X	X			0.2mA	Sensitive SCR	TO-251
Sxx10DS2	X	X			0.2mA	Sensitive SCR	TO-252
Sxx10RS3	X	X			0.5mA	Sensitive SCR	TO-220R
Sxx10LS3	X	X			0.5mA	Sensitive SCR	TO-220L
Sxx10VS3	X	X			0.5mA	Sensitive SCR	TO-251
Sxx10DS3	X	X			0.5mA	Sensitive SCR	TO-252
Sxx10R	X	X	X	X	15mA	Standard SCR	TO-220R
Sxx10L	X	X	X	X	15mA	Standard SCR	TO-220L
Sxx10V	X	X	X	X	15mA	Standard SCR	TO-251
Sxx10D	X	X	X	X	15mA	Standard SCR	TO-252

Note: xx = Voltage

Dimensions — TO-251AA (V/I-Package) — V/I-PAK Through Hole



Dimension	Inches			Millimeters		
	Min	Typ	Max	Min	Typ	Max
A	0.040	0.044	0.050	1.02	1.11	1.27
B	0.235	0.242	0.245	5.97	6.15	6.22
C	0.350	0.361	0.375	8.89	9.18	9.53
D	0.205	0.208	0.213	5.21	5.29	5.41
E	0.255	0.262	0.265	6.48	6.66	6.73
F	0.027	0.031	0.033	0.69	0.80	0.84
G	0.087	0.090	0.093	2.21	2.28	2.36
H	0.085	0.092	0.095	2.16	2.34	2.41
I	0.176	0.180	0.184	4.47	4.57	4.67
J	0.018	0.020	0.023	0.46	0.51	0.58
K	0.038	0.040	0.044	0.97	1.01	1.12
L	0.018	0.020	0.023	0.46	0.52	0.58
P	0.042	0.047	0.052	1.06	1.20	1.32
Q	0.034	0.039	0.044	0.86	1.00	1.11
R	0.034	0.039	0.044	0.86	1.00	1.11
S	0.074	0.079	0.084	1.86	2.00	2.11

Dimensions — TO-252AA (D-Package) — D-PAK Surface Mount



Dimension	Inches			Millimeters		
	Min	Typ	Max	Min	Typ	Max
A	0.040	0.043	0.050	1.02	1.09	1.27
B	0.235	0.243	0.245	5.97	6.16	6.22
C	0.106	0.108	0.113	2.69	2.74	2.87
D	0.205	0.208	0.213	5.21	5.29	5.41
E	0.255	0.262	0.265	6.48	6.65	6.73
F	0.027	0.031	0.033	0.69	0.80	0.84
G	0.087	0.090	0.093	2.21	2.28	2.36
H	0.085	0.092	0.095	2.16	2.33	2.41
I	0.176	0.179	0.184	4.47	4.55	4.67
J	0.018	0.020	0.023	0.46	0.51	0.58
K	0.038	0.040	0.044	0.97	1.02	1.12
L	0.018	0.020	0.023	0.46	0.51	0.58
M	0.000	0.000	0.004	0.00	0.00	0.10
N	0.021	0.026	0.027	0.53	0.67	0.69
O	0°	0°	5°	0°	0°	5°
P	0.042	0.047	0.052	1.06	1.20	1.32
Q	0.034	0.039	0.044	0.86	1.00	1.11

Dimensions — TO-220AB (R-Package) — Non-Isolated Mounting Tab Common with Center Lead



Dimension	Inches		Millimeters	
	Min	Max	Min	Max
A	0.380	0.420	9.65	10.67
B	0.105	0.115	2.67	2.92
C	0.230	0.250	5.84	6.35
D	0.590	0.620	14.99	15.75
E	0.142	0.147	3.61	3.73
F	0.110	0.130	2.79	3.30
G	0.540	0.575	13.72	14.61
H	0.025	0.035	0.64	0.89
J	0.195	0.205	4.95	5.21
K	0.095	0.105	2.41	2.67
L	0.060	0.075	1.52	1.91
M	0.085	0.095	2.16	2.41
N	0.018	0.024	0.46	0.61
O	0.178	0.188	4.52	4.78
P	0.045	0.060	1.14	1.52
R	0.038	0.048	0.97	1.22

Dimensions — TO-220AB (L-Package) — Isolated Mounting Tab



Dimension	Inches		Millimeters	
	Min	Max	Min	Max
A	0.380	0.420	9.65	10.67
B	0.105	0.115	2.67	2.92
C	0.230	0.250	5.84	6.35
D	0.590	0.620	14.99	15.75
E	0.142	0.147	3.61	3.73
F	0.110	0.130	2.79	3.30
G	0.540	0.575	13.72	14.61
H	0.025	0.035	0.64	0.89
J	0.195	0.205	4.95	5.21
K	0.095	0.105	2.41	2.67
L	0.060	0.075	1.52	1.91
M	0.085	0.095	2.16	2.41
N	0.018	0.024	0.46	0.61
O	0.178	0.188	4.52	4.78
P	0.045	0.060	1.14	1.52
R	0.038	0.048	0.97	1.22

Packing Options

Part Number	Marking	Weight	Packing Mode	Base Quantity
Sxx10L/Ryy	Sxx10L/Ryy	2.2 g	Bulk	500
Sxx10L/RyyTP	Sxx10L/Ryy	2.2 g	Tube	500 (50 per tube)
Sxx10DyyTP	Sxx10Dyy	0.3 g	Tube	750 (75 per tube)
Sxx10DyyRP	Sxx10Dyy	0.3 g	Embossed Carrier	2500
Sxx10VyyTP	Sxx10Vyy	0.4 g	Tube	750 (75 per tube)
Sxx10L/R	Sxx10L/R	2.2 g	Bulk	500
Sxx10L/RTP	Sxx10L/R	2.2 g	Tube	500 (50 per tube)
Sxx10DTP	Sxx10D	0.3 g	Tube	750 (75 per tube)
Sxx10DRP	Sxx10D	0.3 g	Embossed Carrier	2500
Sxx10VTP	Sxx10V	0.4 g	Tube	750 (75 per tube)

Note: xx = Voltage; yy = Sensitivity

TO-252 Embossed Carrier Reel Pack (RP) Specifications

Meets all EIA-481-2 Standards



Part Numbering System



Part Marking System

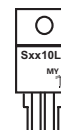
TO-220 AB – (R Package)



TO-251AA – (V Package)
TO-252AA – (D Package)



TO-220 AB – (L Package)



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- Широкая линейка поставок активных и пассивных импортных электронных компонентов (более 30 млн. наименований);
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- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
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- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

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«FORSTAR» (основан в 1998 г.)

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